



Lecture – 5

Date: 20.08.2015

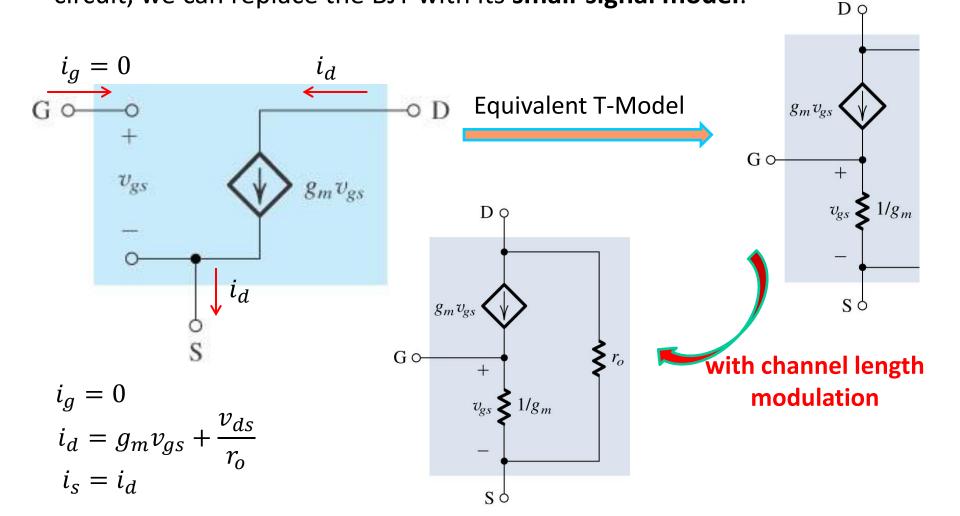
- MOSFET Small Signal Models, and Analysis
- Common Source Amplifier Introduction





MOSFET – Small Signal Model

To determine the small-signal performance of a given MOSFET amplifier circuit, we can replace the BJT with its **small-signal model**:







MOSFET – Small Signal Model (contd.)

• Recall that due to channel-length modulation, the MOSFET drain current is slightly dependent on v_{DS} , and thus is more accurately described as:

$$i_D = K \left(v_{GS} - V_T \right)^2 \left(1 + \lambda v_{DS} \right)$$

• In order to determine the relationship between the small-signal voltage v_{gs} and small-signal current i_d we can apply a **small signal analysis** of this equation:

$$i_d = \frac{di_D}{dv_{GS}}\Big|_{v_{GS} = V_{GS}} \left(v_{gs}\right) \qquad \qquad i_d = 2K\left(V_{GS} - V_T\right)v_{gs} \qquad \qquad \therefore i_d = g_m v_{gs}$$

Note that we evaluated the derivative at the DC bias point V_{GS} . The result, as we expected, was the transconductance ${\bf g}_{\bf m}$





MOSFET – Small Signal Model (contd.)

• We can likewise determine the relationship between small-signal voltage v_{ds} and the small-signal current i_d :

$$i_d = \frac{di_D}{dv_{DS}}\Big|_{v_{GS} = V_{GS}} \left(v_{ds}\right) \qquad \qquad i_d = \lambda K \left(V_{GS} - V_T\right)^2 v_{ds} \qquad \qquad \therefore i_d = \frac{v_{ds}}{r_o}$$

• where we **recall** that r_o is the MOSFET **output resistance**:

$$r_o = \frac{1}{\lambda K (V_{GS} - V_T)^2} \qquad \qquad r_o = \frac{1}{\lambda I_D}$$

• The small signal drain current i_d of a MOSFET (biased at a DC operating point V_{GS} and I_D) is therefore:

$$i_d = g_m v_{gs} + \frac{v_{ds}}{r_o}$$





MOSFET – Small Signal Analysis Steps

 Complete each of these steps if you choose to correctly complete a MOSFET Amplifier small-signal analysis.

Step 1: Complete a **D.C. Analysis**

Turn off all small-signal sources, and then complete a circuit analysis with the remaining D.C. sources only.

- Complete this DC analysis exactly, precisely, the same way you performed the DC analysis in **lecture-3**. That is, you assume (the **saturation** mode), enforce, analyze, and **check (do not forget to check!)**.
- Note that you enforce and check exactly, precisely the same equalities and inequalities as discussed in **lecture-3**.
- Remember, if we "turn off" a **voltage** source (e.g., $v_i(t) = 0$), it becomes a **short** circuit.
- However, if we "turn off" a current source (e.g., $i_i(t)=0$), it becomes an open circuit!





Step 1: Complete a **D.C. Analysis (contd.)**

- Small-signal amplifiers frequently employ large capacitors. Remember, the impedance of a capacitor at DC is infinity—a DC open circuit.
- The goal of this DC analysis is to determine:
 - 1) The DC voltage V_{GS} for **each** MOSFET.
 - 2) The DC voltage V_{DS} for **each** MOSFET (you need this value for the CHECK).

You do not **necessarily** need to determine any other DC currents or voltages within the amplifier circuit!

Once you have found these values, you can **CHECK** your saturation assumption, and then move on to **step 2**.

Step 2: Calculate the small-signal circuit parameters for each MOSFET.

$$g_m = 2K(V_{GS} - V_T)$$

$$r_o = \frac{1}{\lambda K(V_{GS} - V_T)^2}$$



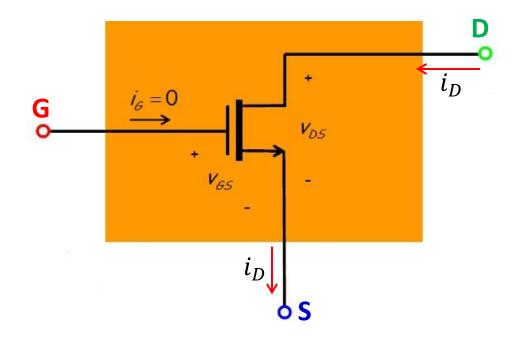


Step 3: Carefully replace all MOSFETs with their **small-signal circuit model.**

This step often gives students **fits**!

However, it is actually a **very simple** and straight-forward step. It does require four important things from the student— **patience**, **precision**, **persistence** and **professionalism**!

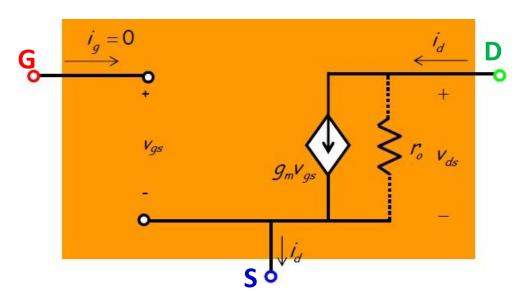
• First, note that a **MOSFET** is: a device with **three** terminals, called the gate, drain, and source. Its behavior is described in terms of current i_D and voltages v_{GS} , v_{DS} .







• Now, **contrast** the MOSFET with its small-signal circuit model. A MOSFET small-signal circuit model is: a device with **three** terminals, called the gate, drain, and source. Its behavior is described in terms of current i_d and voltages v_{gs} , v_{ds} .



Exactly the **same**—what a coincidence!

Therefore, replacing a MOSFET with its small-signal circuit model is very simple—you simply change the stuff **within** the orange box!





- Note the parts of the circuit external to the orange box do not change! In other words:
 - 1) every device attached to the MOSFET terminals (i.e, gate, drain, source) is attached in **precisely** the same way to the terminals of the circuit model.
 - **2) every** external voltage or current (e.g., v_i, v_o, i_R) is defined in **precisely** the same way both before and after the MOSFET is replaced with its circuit model is (e.g., if the output voltage is the drain voltage in the MOSFET circuit, then the output voltage is **still** the drain voltage in the small-signal circuit!).

Step 4: Set all **D.C. sources** to zero.

- A zero voltage DC source is a short.
- A zero current DC source is an open.
- Replace the large capacitors with a (AC) short.

The schematic now in front of you is called the **small-signal circuit**. Note that it is **missing** two things—**DC sources** and MOSFET **transistors**!





Note that steps three and four are reversible. You could turn off the DC sources first, and then replace all MOSFETs with their small-signal models—the resulting small-signal circuit will be the same!

Step 5: Analyze **small-signal circuit**.

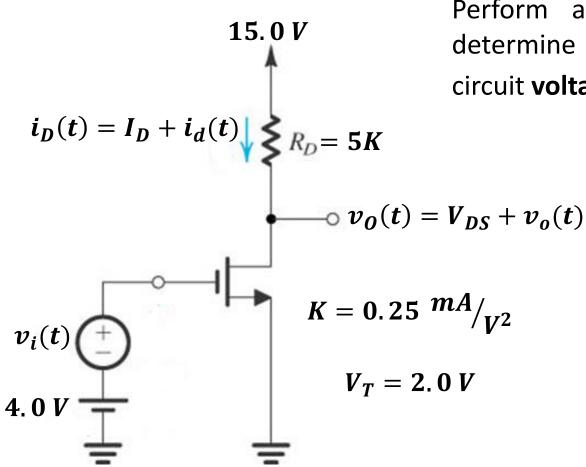
- For small-signal **amplifiers**, we typically attempt to find the small-signal output voltage v_o in terms of the small-signal input voltage v_i . From this result, we can find the **voltage gain** of the amplifier.
- Do not attempt to insert any MOSFET knowledge into your small-signal circuit analysis—there are no MOSFETs in a small-signal circuit!!!!!
- Remember, the MOSFET circuit model contains all of our MOSFET small-signal knowledge, we do not—indeed must not—add any more information to the analysis.

You must **trust** completely the MOSFET small-signal circuit model. It **will** give you the correct answer!





Example – 1



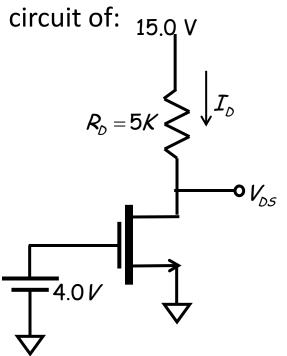
Perform a small-signal analysis to determine the small-signal open-circuit **voltage gain** $A_v = \frac{v_o(t)}{v_i(t)}$





Step 1: DC Analysis

 Turning off the small signal source leaves a DC circuit of: 15 0 V



• We CHECK our results and find:

$$V_{GS} = 4.0 > V_{t} = 2.0$$

• We **ASSUME** saturation, so that we **ENFORCE**:

$$I_D = K(V_{GS} - V_t)^2$$

- It is evident that: $V_{GS} = 4.0 \text{ V}$
- Therefore the DC drain current is:

$$I_D = K (V_{GS} - V_t)^2$$

= 0.25(4 - 2)²
= 1.0 mA

• Thus, the DC voltage V_{DS} can be determined from KVL as:

$$V_{DS} = 15.0 - I_{D}R_{D}$$

= 15.0 - 1(5)
= 10.0 V

$$V_{DS} = 10.0 > V_{GS} - V_{t} = 2.0$$





Step 2: Determine the small-signal parameters

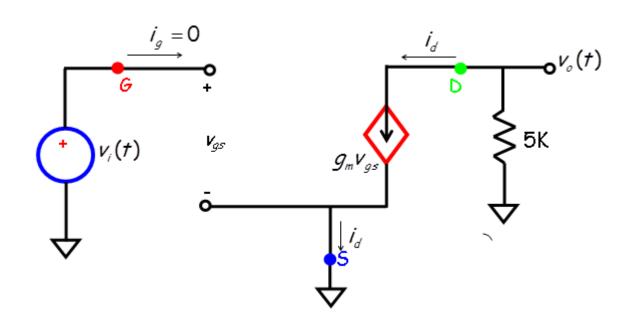
$$g_m = 2K(V_{GS} - V_t)$$

= 2(0.25)(4.0 - 2.0)
= 1 mA/V

• Note that **no** value of λ was given, so we will assume $\lambda = 0$, and thus **output resistance** $r_o = \infty$.

Steps 3 and 4: Determine the small-signal circuit

We now turn off the **two** DC voltage source, and replace the MOSFET with its **small signal model**. The result is our **small-signal circuit**.







Step 5: Analyze the small-signal circuit

The analysis of this small-signal circuit is fairly $V_{qs} = V_{j}$ **straightforward**. First, we note from KVL that:

we note from KVL that:
$$v_{gs} = v_i$$

and that:

$$i_d = g_m v_{gs}$$

$$= 1.0 v_{gs}$$

$$= v_{gs}$$

and that from Ohm's Law:

$$v_o = -5i_d$$

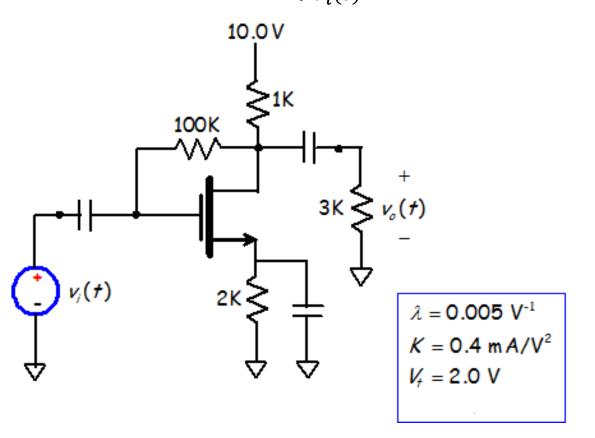
- **Combining** these equations, we find that: $V_o = -5 V_i$
- $A_o = \frac{V_o(t)}{V_o(t)} = -5.0$ And thus the **small-signal** open-circuit voltage gain of this amplifier is:





Example – 2

• Perform a small-signal analysis to determine the small-signal open-circuit voltage gain $A_v={^{v_o(t)}/_{v_i(t)}}$



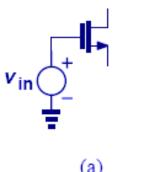
Here the C's are large

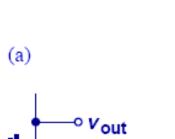




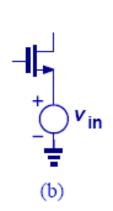
Single Stage CMOS Amplifier

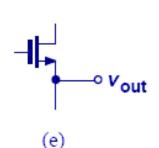
Possible I/O Connections to a MOS transistor

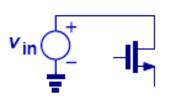












(c)



(f)

Of all the possible I/O connections to a MOS transistor, only (a,d), (a,e) and (b,d) are functional.

I/O connections (a,d):
 Common Source (CS)

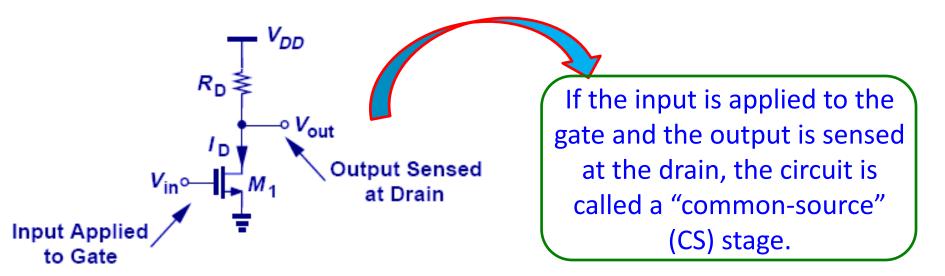
I/O connections (a,e):
Common Drain (CD)

I/O connections (b,d):
 Common Gate (CG)





Common Source (CS) Amplifier



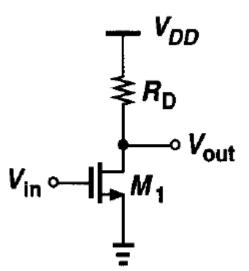
From now on: to make it simple, all the voltages and currents will be mentioned beforehand whether in that particular context it denotes dc+ac, ac or only dc.

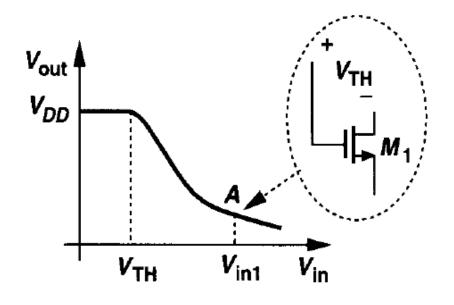




Common Source (CS) Amplifier

Large Signal Analysis





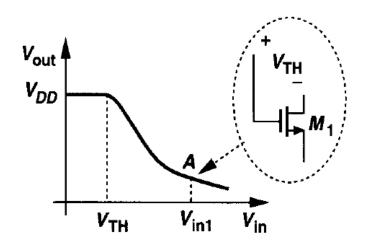
- If V_{in} (signal+dc) increases from zero, M₁ is off and V_{out} = V_{DD}.
- M_1 begins to turn on once V_{in} reaches $V_T \rightarrow$ draws current from R_D and lowers V_{out} . For adequate level of V_{DD} , M_1 turns on in saturation and we have:

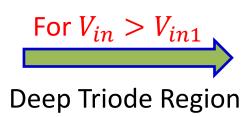
$$V_{out} = V_{DD} - R_D \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{in} - V_T)^2$$

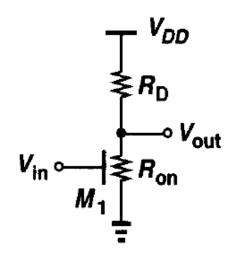




Common Source (CS) Amplifier (contd.)







$$V_{out} = V_{DD} \frac{R_{on}}{R_{on} + R_{DD}}$$





Common Source (CS) Amplifier (contd.)

- For the transistor's operation in the saturation region $(V_{out} > V_{in} V_T)$, i.e, in the region left of point A.
 - → the small signal gain is:

$$A_{v} = \frac{\partial V_{out}}{\partial V_{in}} = -R_{D} \mu_{n} C_{ox} \frac{W}{L} (V_{in} - V_{T})$$

$$\Rightarrow A_{v} = -g_{m} R_{D}$$

$$\Rightarrow A_{v} = -g_{m} R_{D}$$

• This can also be obtained from a simple observation $\rightarrow M_1$ converts input voltage change ΔV_{in} to a drain current change $g_m \Delta V_{in} \rightarrow$ hence an output voltage change $-g_m R_D \Delta V_{in}$.

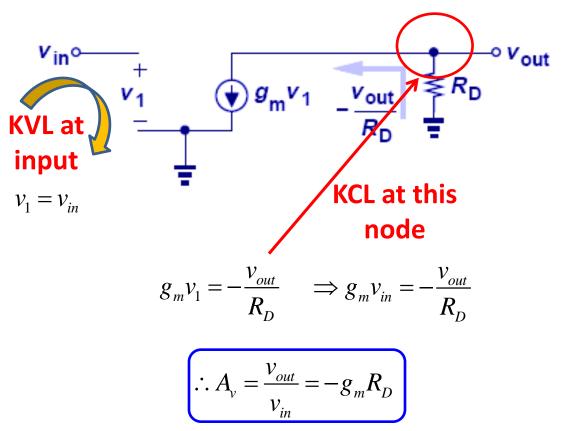
$$\Rightarrow A_{v} = \frac{\Delta V_{out}}{\Delta V_{in}} = -\frac{g_{m}R_{D}\Delta V_{in}}{\Delta V_{in}} = -g_{m}R_{D}$$





Common Source (CS) Amplifier (contd.)

Alternatively, let us look through the small signal representation of the CS stage:

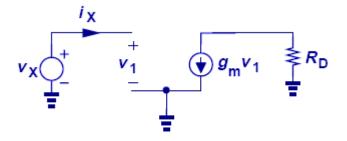




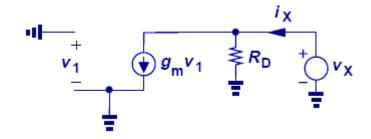


Common Source (CS) Amplifier (contd.)

Input and Output Impedances:



$$R_{in} = \frac{V_x}{I_x} = \infty$$



$$R_{out} = \frac{V_x}{I_x} = R_D$$





Common Source (CS) Amplifier (contd.)

Observations and Discussions

$$A_{v} = -g_{m}R_{D}$$

- g_m changes substantially if the input signal is large → if the gain changes significantly with the signal swing then the circuit operates in large signal mode.
- The dependence of the gain (A_v) upon the signal level leads to nonlinearity → undesirable condition.
- To minimize the nonlinearity, the gain (A_v) should be a weak function of $g_m \rightarrow design$ and layout of amplifier circuit critical.





Common Source (CS) Amplifier (contd.)

Alternative expression for gain:
$$\Rightarrow A_{v} = -\sqrt{2\mu_{n}C_{ox}\frac{W}{L}\frac{V_{RD}}{\sqrt{I_{D}}}}$$
 V_{RD}: voltage drop across R_D

- A_v can be increased by increasing W/L or V_{RD} or decreasing I_D if other parameters are fixed.
- However, large W/L leads to greater device capacitance, and a higher **V_{RD}** limits the maximum voltage swings.
- If V_{RD} remains constant and I_{D} is reduced, then R_{D} must increase \rightarrow results in greater time constant at the output node.
- In addition, for large R_D the effect of channel length modulation comes into play and therefore the output voltage becomes:

$$V_{out} = V_{DD} - R_D \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{in} - V_T)^2 (1 + \lambda V_{out})$$





Common Source (CS) Amplifier (contd.)

$$A_{v} = \frac{\partial V_{out}}{\partial V_{in}} = -R_{D}\mu_{n}C_{ox}\frac{W}{L}(V_{in} - V_{T})(1 + \lambda V_{out}) - R_{D}\frac{1}{2}\mu_{n}C_{ox}\frac{W}{L}(V_{in} - V_{T})^{2}\lambda\frac{\partial V_{out}}{\partial V_{in}}$$

$$\Rightarrow A_{v} = -R_{D}g_{m} - R_{D}I_{D}\lambda A_{v}$$

$$\Rightarrow A_{v} = -R_{D}g_{m} - R_{D}I_{D}\lambda A_{v} \qquad \qquad \underline{\text{Where,}} \quad I_{D} \approx -R_{D}\frac{1}{2}\mu_{n}C_{ox}\frac{W}{L}(V_{in} - V_{T})^{2}$$

$$\therefore A_{v} = -\frac{g_{m}R_{D}}{1 + R_{D}\lambda I_{D}}$$

$$\therefore A_{v} = -\frac{g_{m}R_{D}}{1 + R_{D}\lambda I_{D}} \qquad \Longrightarrow A_{v} = -g_{m}\frac{r_{o}R_{D}}{r_{o} + R_{D}} \qquad \text{Where,} \quad r_{o} = \frac{1}{\lambda I_{D}}$$

Eventual





Common Source (CS) Amplifier (contd.)

Alternatively, the same expression can be achieved from following small signal model:

